2SA1290/2SC3254



60V/7A High-Speed Switching Applications

Applications

- · Various inductance lamp drivers for electrical equipment.
- · Inverters, converters (strobo, flash, fluorescent lamp lighting circuit).
- · Power amp (high power car stereo, motor controller).
- · High-speed switching (switching regulator, driver).

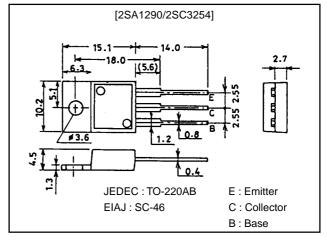
Features

- · Low saturation voltage.
- · Excellent current dependence of h_{FE}.
- · Short switching time.

Package Dimensions

unit:mm

2010B



(): 2SA1290

Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V _{СВО}		(–)80	V
Collector-to-Emitter Voltage	VCEO		(–)60	V
Emitter-to-Base Voltage	VEBO		(-)5	V
Collector Current	IC		(-)7	Α
Collector Current (Pulse)	I _{CP}		(-)10	Α
Collector Dissipation	PC	Tc=25°C	35	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

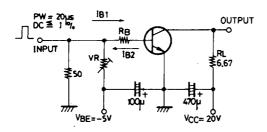
Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions	Ratings			Unit
Falanielei	Symbol	Symbol		typ	max	Offit
Collector Cutoff Current	ІСВО	V _{CB} =(-)40V, I _E =0			(-)0.1	mA
Emitter Cutoff Current	I _{EBO}	V _{EB} =(-)4V, I _C =0			(-)0.1	mA
DC Current Gain	hFE	V _{CE} =(-)2V, I _C =(-)1A			280*	
Gain-Bandwidth Product		V _{CE} =(-)5V, I _C =(-)1A		100		MHz
Collector-to-Emitter Saturation Voltage V		I _C =(-)3.5A, I _B =(-)0.175A			(-)0.4	V
Collector-to-Base Breakdown Voltage	V(BR)CBO	I _C =(-)1mA, I _E =0	(–)80			V
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	I _C =(−)1mA, R _{BE} =∞	(-)60			V
Emitter-to-Base Breakdown Voltage	V(BR)EBO	I _E =(-)1mA, I _C =0	(-)5			V
Turn-ON Time	ton	See specified Test Circuit		0.1		μs
Storage Time	t _{stg}	See specified Test Circuit		0.5		μs
Fall Time	t _f	See specified Test Circuit		0.1		μs

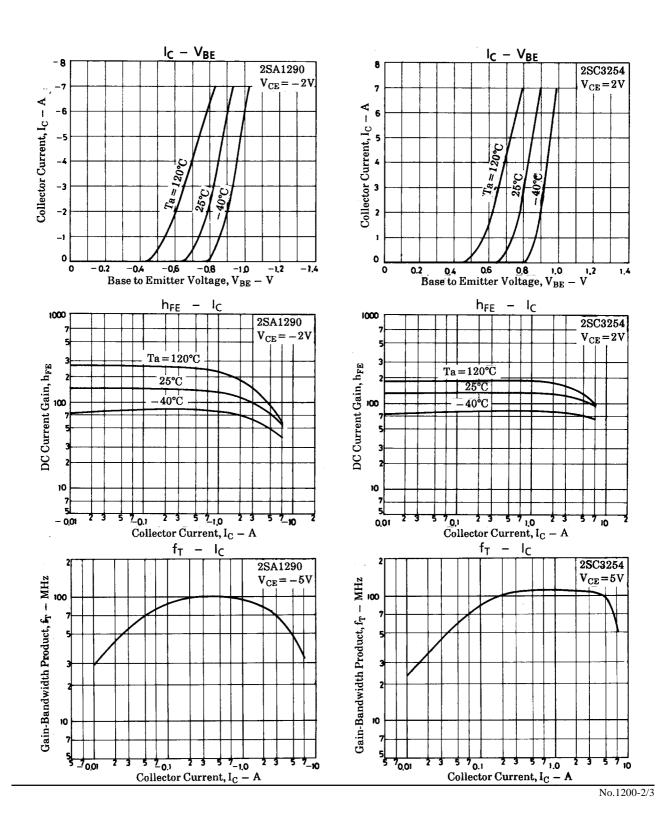
 $[\]mbox{\ensuremath{^{*}}}$: The 2SA1290/2SC3254 are classified by 1A $\mbox{\ensuremath{h_{FE}}}$ as follows

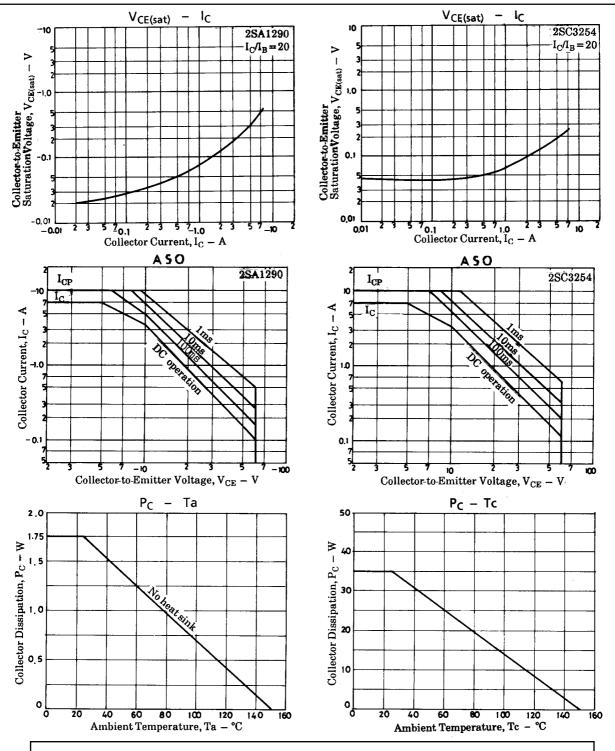
1		_			_			_	
1	70	(J	140	100	R	200	140	S	280

Switching Time Test Circuit



(For PNP, the polarity is reversed)20I_{B1}= $-20I_{B2}$ =I_C=3A Unit (resistance : Ω , capacitance : F)





- No products described or contained herein are intended for use in surgical implants, life-support systems, aerospace equipment, nuclear power control systems, vehicles, disaster/crime-prevention equipment and the like, the failure of which may directly or indirectly cause injury, death or property loss.
- Anyone purchasing any products described or contained herein for an above-mentioned use shall:
 - ① Accept full responsibility and indemnify and defend SANYO ELECTRIC CO., LTD., its affiliates, subsidiaries and distributors and all their officers and employees, jointly and severally, against any and all claims and litigation and all damages, cost and expenses associated with such use:
 - ② Not impose any responsibilty for any fault or negligence which may be cited in any such claim or litigation on SANYO ELECTRIC CO., LTD., its affiliates, subsidiaries and distributors or any of their officers and employees jointly or severally.
- Information (including circuit diagrams and circuit parameters) herein is for example only; it is not guaranteed for volume production. SANYO believes information herein is accurate and reliable, but no guarantees are made or implied regarding its use or any infringements of intellectual property rights or other rights of third parties.

This catalog provides information as of July, 1998. Specifications and information herein are subject to change without notice.